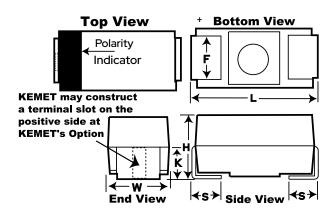


T495X108M006ZTE100

Obsolete

B450, Tantalum, MnO2 Tantalum, 1,000 uF, 20%, 6.3 VDC, SMD, Molded, Low ESR, Surge Robust, 100 mOhms, 7343, 4.4 mm, 1.3 mm



General Information	
Series	B450
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, Low ESR, Surge Robust
Features	Low ESR, Surge Robust
RoHS	Yes
Termination	Tin
AEC-Q200	No

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	4.1mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Specifications	
Capacitance	1,000 uF
Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.1 Ohms (100kHz)
Ripple Current	1280 mAmps (25C), 1152 mAmps (85C), 512 mAmps (125C)
Leakage Current	63 uA

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	400

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Generated 04/01/2025 © 2006 - 2025 YAGEO